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# HL6720G

AlGaInP Laser Diode

**HITACHI**

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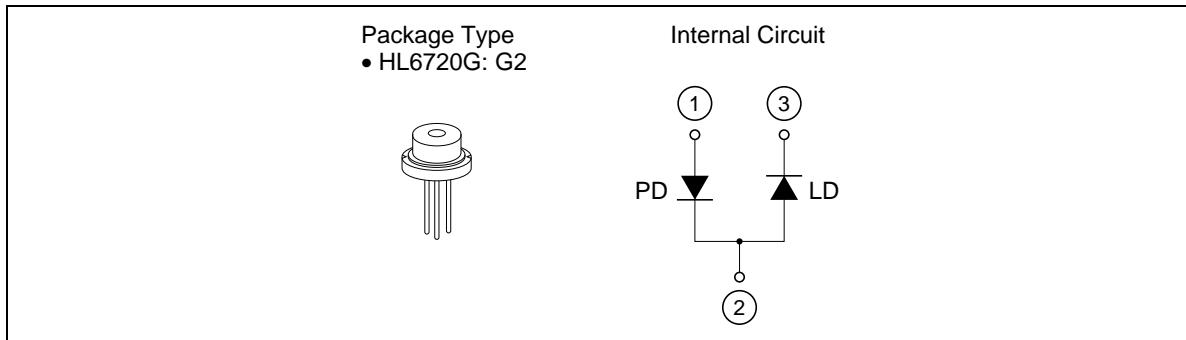
## Description

The HL6720G is a 0.67  $\mu\text{m}$  band AlGaInP index-guided laser diode with a double heterostructure.

It is suitable as a light source for pointers, and various other types of optical equipment. Hermetic sealing of the package assures high reliability.

## Features

- Visible light output at wavelengths up to 680 nm
- Continuous operating output: 5 mW CW
- Low voltage operation: 2.7 V Max
- Single longitudinal mode
- Built-in monitor photodiode



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## HL6720G

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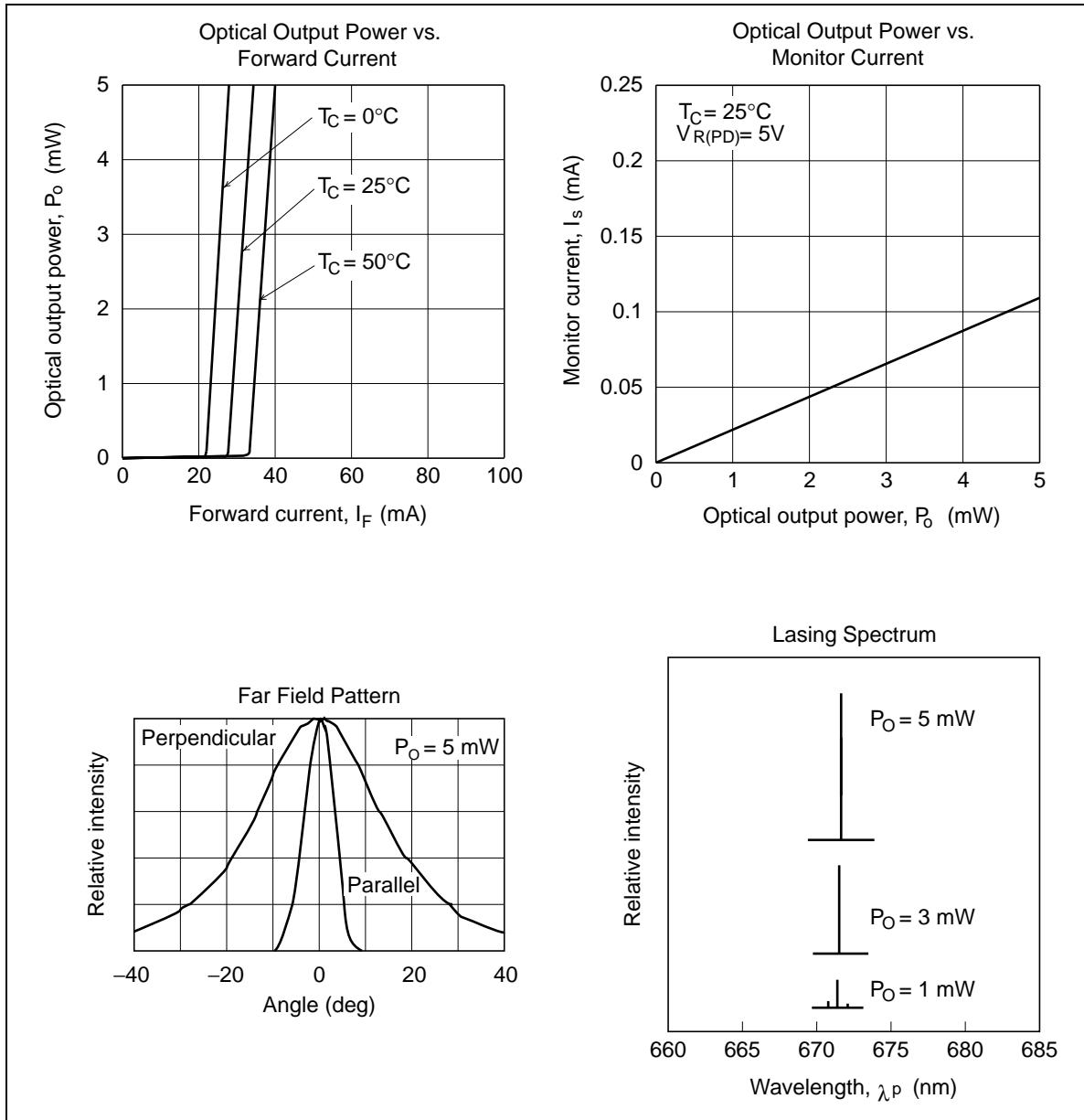
### Absolute Maximum Ratings ( $T_c = 25^\circ\text{C}$ )

Item	Symbol	Rated Value	Unit
Optical output power	$P_o$	5	mW
Pulse optical output power	$P_{o(\text{pulse})}$	$6^{\ast 1}$	mW
LD reverse voltage	$V_{R(\text{LD})}$	2	V
PD reverse voltage	$V_{R(\text{PD})}$	30	V
Operating temperature	$T_{opr}$	-10 to +50	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-40 to +85	$^\circ\text{C}$

Note: 1. Maximum 50% duty cycle, maximum 1  $\mu\text{s}$  pulse width

### Optical and Electrical Characteristics ( $T_c = 25^\circ\text{C}$ )

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Optical output power	$P_o$	5	—	—	mW	Kink free
Threshold current	$I_{th}$	—	30	60	mA	
Slope efficiency	$\eta$	0.4	—	1.0	mW/mA	$3 \text{ mW} / I_{(4 \text{ mW})} - I_{(1 \text{ mW})}$
LD operating current	$I_{op}$	—	35	70	mA	$P_o = 5 \text{ mW}$
LD operating voltage	$V_{op}$	—	—	2.7	V	$P_o = 5 \text{ mW}$
Lasing wavelength	$\lambda_p$	660	670	680	nm	$P_o = 5 \text{ mW}$
Beam divergence (parallel)	$\theta_{//}$	6	9	12	deg.	$P_o = 5 \text{ mW}$
Beam divergence (perpendicular)	$\theta_{\perp}$	20	30	40	deg.	$P_o = 5 \text{ mW}$
Monitor current	$I_s$	0.03	—	0.2	mA	$P_o = 5 \text{ mW}, V_R = 5 \text{ V}$

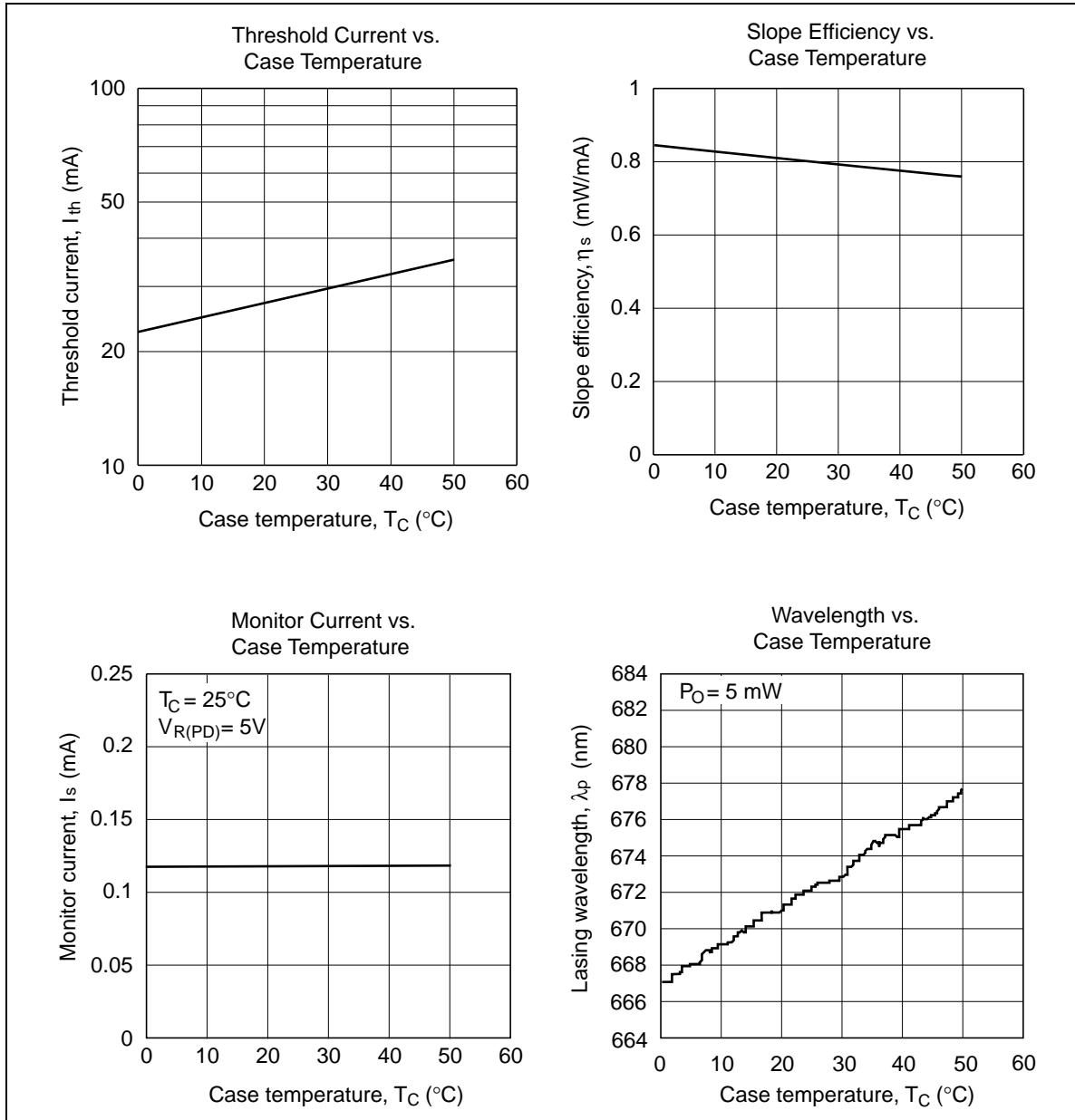
**Typical Characteristic Curves**

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## HL6720G

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### Typical Characteristic Curves (cont)



**Typical Characteristic Curves (cont)**